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| FORM PTO-1449 | | Atty. Docket No. XA-9907 | Appln. No. W/616 923 |
| LIST OF DOCUMENTS CITED BY APPLICANT | | Applicant Haruki FUKAI et al. | |
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U.S. PATENT DOCUMENTS

| Examiner Initial | | Document Number | Date | Name | Class | Sub-class | Filing Date |
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| | AA | | | | | | |
| | AB | | | | | | |
| | AC | | | | | | |
| | AD | | | | | | |
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FOREIGN PATENT DOCUMENTS

| Examiner Initial | | Document Number | Date | Country | Class | Sub-class | Translation |
|------------------|----|-----------------|------|---------|-------|-----------|-------------|
| | AJ | | | | | | |
| | AK | | | | | | |
| | AL | | | | | | |
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| | AN | | | | | | |
| | AO | | | | | | |

OTHER (including author, title, date, pertinent pages, etc.)

| | | |
|-----------|----|---|
| WP | AP | Ito et al. ed., "Handoutai Laser (Semiconductor Laser)," Baifukan, 1991, Chapter 5 (Kayane). |
| WP | AQ | Lin et al., "High-Temperature, Low Threshold Current, and Uniform Operation 1x12 Monolithic AlGaInAs/InP Strain-Compensated Multiple Quantum Well Laser Array in 1.5 μ m," <u>IEEE Transactions on Electron Devices</u> , August 1999, Vol. 46, No. 8, pp. 1614-1618. |
| | AR | |

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| Examiner <i>[Signature]</i> | Date Considered 06/27/05 |
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.